



PTB 20146

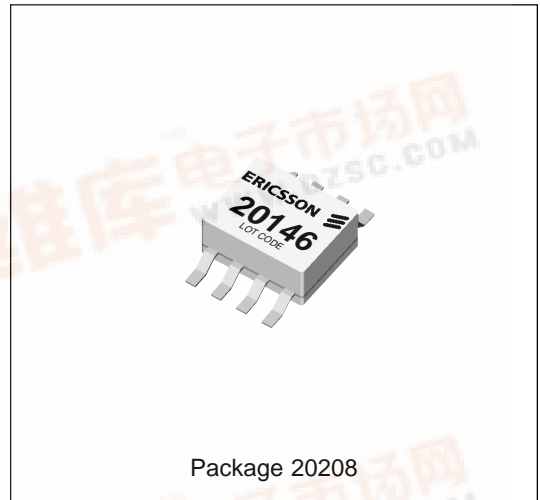
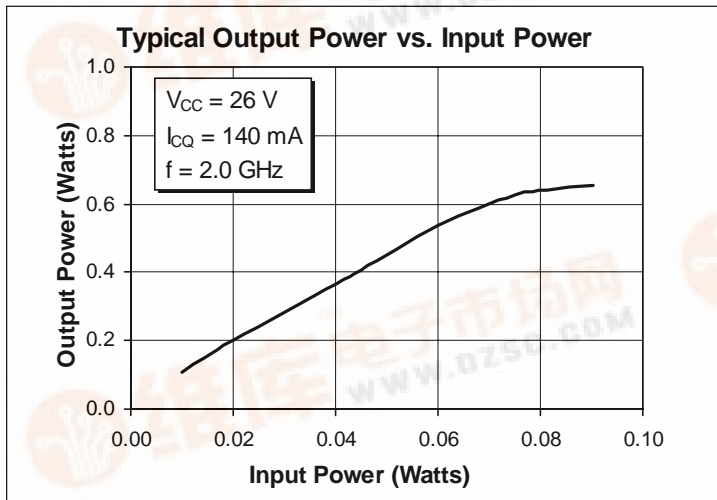
0.4 Watt, 1.8–2.0 GHz

Cellular Radio RF Power Transistor

Description

The 20146 is a class A, NPN, common emitter RF power transistor intended for 26 Vdc operation from 1.8 to 2.0 GHz. Rated at 0.4 watt minimum output power, it may be used for both CW and PEP applications. Ion implantation, nitride surface passivation and gold metallization are used to ensure excellent device reliability. 100% lot traceability is standard.

- 0.4 Watt, 1.8–2.0 GHz
- Class A Characteristics
- Tested to solderability standards:
 - IEC-68-2-54
 - ANSI/J Std-002-A
- Gold Metallization
- Silicon Nitride Passivated
- Surface Mountable
- Available in Tape and Reel



Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CER}	50	Vdc
Collector-Base Voltage	V_{CBO}	50	Vdc
Emitter-Base Voltage (collector open)	V_{EBO}	4.0	Vdc
Collector Current (continuous)	I_C	0.5	Adc
Total Device Dissipation at $T_{flange} = 25^\circ C$ Above $25^\circ C$ derate by	P_D	5.4 0.031	Watts W/ $^\circ C$
Storage Temperature Range	T_{STG}	-40 to +150	$^\circ C$
Thermal Resistance ($T_{flange} = 70^\circ C$)	$R_{\theta JC}$	32.3	$^\circ C/W$

Electrical Characteristics (100% Tested)

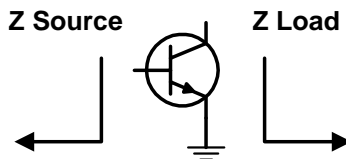
Characteristic	Conditions	Symbol	Min	Typ	Max	Units
Breakdown Voltage C to E	$I_B = 0\text{ A}, I_C = 10\text{ mA}, R_{BE} = 22\ \Omega$	$V_{(BR)CER}$	50	—	—	Volts
Breakdown Voltage C to E	$V_{BE} = 0\text{ V}, I_C = 5\text{ mA}$	$V_{(BR)CES}$	50	—	—	Volts
Breakdown Voltage E to B	$I_C = 0\text{ A}, I_E = 5\text{ mA}$	$V_{(BR)EBO}$	4	5	—	Volts
DC Current Gain	$V_{CE} = 5\text{ V}, I_C = 250\text{ mA}$	h_{FE}	20	40	—	—

RF Specifications (100% Tested)

Characteristic	Symbol	Min	Typ	Max	Units
Gain ($V_{CC} = 26\text{ Vdc}, P_{out} = 0.4\text{ W}, I_{CQ} = 140\text{ mA}, f = 2.0\text{ GHz}$)	G_{pe}	8	10	—	dB
Output Power at 1 dB Compressed ($V_{CC} = 26\text{ Vdc}, I_{CQ} = 140\text{ mA}, f = 2.0\text{ GHz}$)	P-1dB	0.4	0.6	—	Watts
Load Mismatch Tolerance ($V_{CC} = 26\text{ Vdc}, P_{out} = 0.4\text{ W}, I_{CQ} = 140\text{ mA}, f = 2.0\text{ GHz}$ —all phase angles at frequency of test)	Ψ	—	—	5:1	—

Impedance Data (data shown for fixed-tuned broadband circuit)

($V_{CC} = 26\text{ Vdc}, P_{out} = 0.4\text{ W}, I_{CQ} = 140\text{ mA}$)



Frequency	Z Source		Z Load	
	R	jX	R	jX
1.800	18.8	3.0	5.8	22.0
1.900	18.1	5.3	8.6	22.4
2.000	18.1	9.3	5.0	21.6